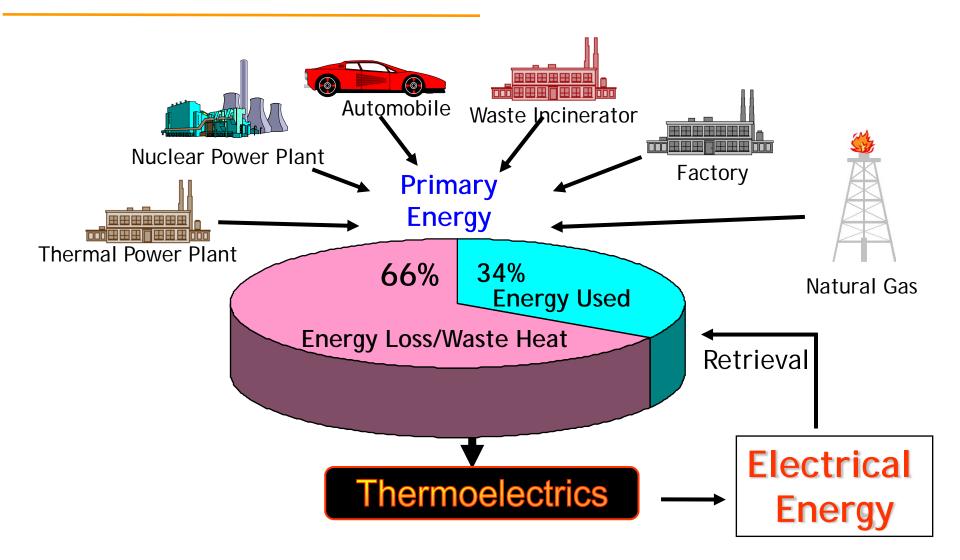


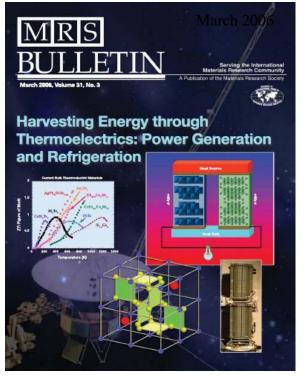
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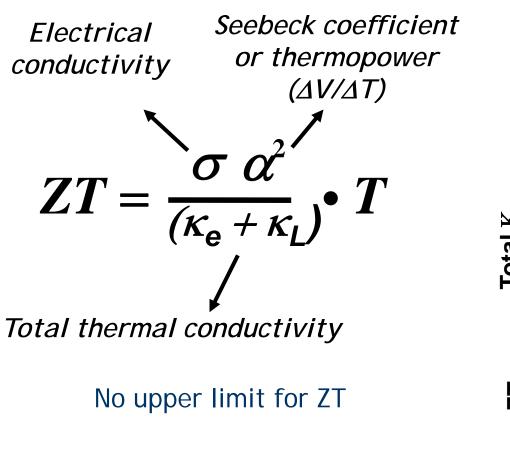
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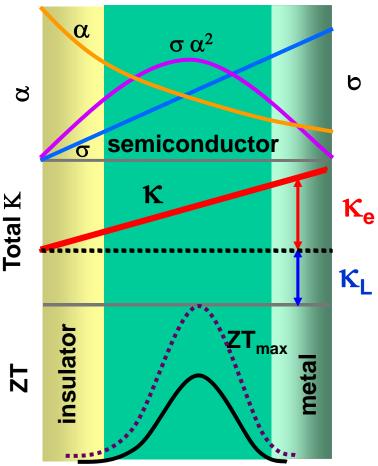
Guest Editors: Tritt and Subramanian Thermoelectric Materials, Phenomena, and Applications: A Bird's Eye View: T. M. Tritt, M. A.Subramanian

Recent Developments in Bulk Thermoelectric Materials: G. S. Nolas, M. Kanatzidis

Properties of Nanostructured One-Dimensional and Composite: Thermoelectric Materials : A. M. Rao, X. Ji, and T. M. Tritt

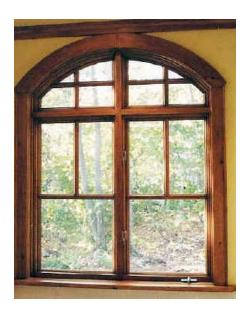


Contra-indicated Properties



10¹⁷10¹⁸ 10¹⁹10²⁰10²¹ Carrier Concentration

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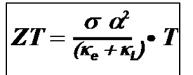


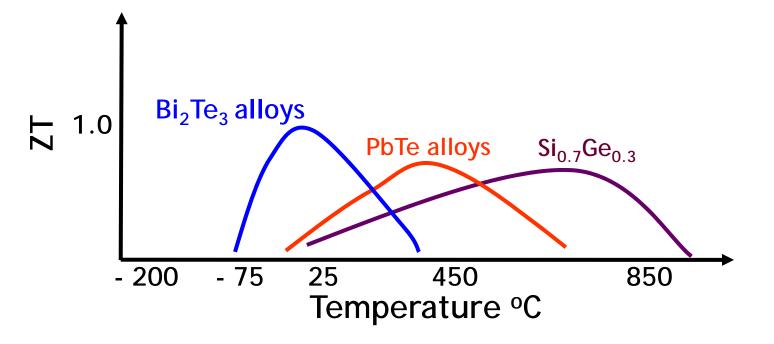
Glass (amorphous) Very low

Metal High *thermal conductivity* electrical conductivity

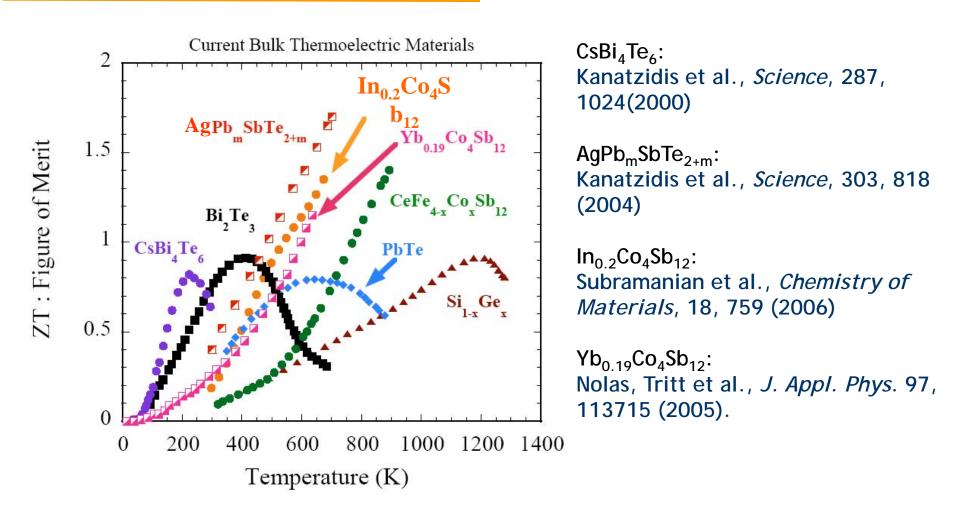
Semiconductor High Thermopower

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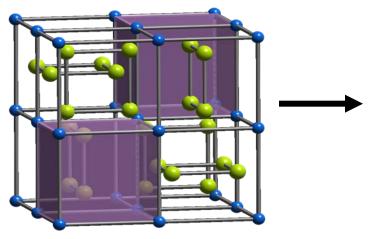




- Narrow band gap semiconductors (increasing numerator)
- Elements of high atomic weight e.g. Bi, Pb, Hg, Te (decreasing the denominator)

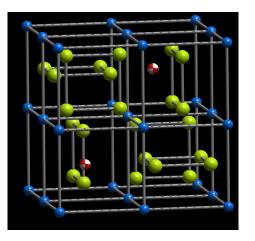


 $ZT = \frac{\sigma \alpha^2}{(\kappa_e + \kappa_r)} \bullet T$



 Co_4Sb_{12}

Large numerator Large Denominator ZT ~ 0.4 at 600K



 $R_xCo_4Sb_{12}$ (R = Rare-earth, In)

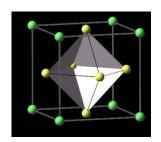
Large numerator Small denominator ZT~ 1.3 at 600K

Subramanian et al., *Chemistry of Materials*, 18, 759 (2006) Nolas, Tritt et al., *J. Appl. Phys.* 97, 113715 (2005) Singh et al., *Phys. Rev.* B 53, 6273 (2003)

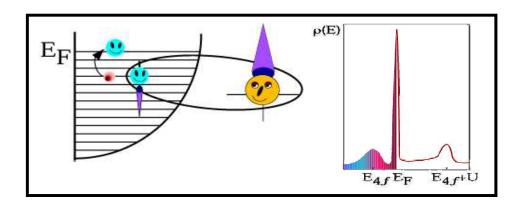
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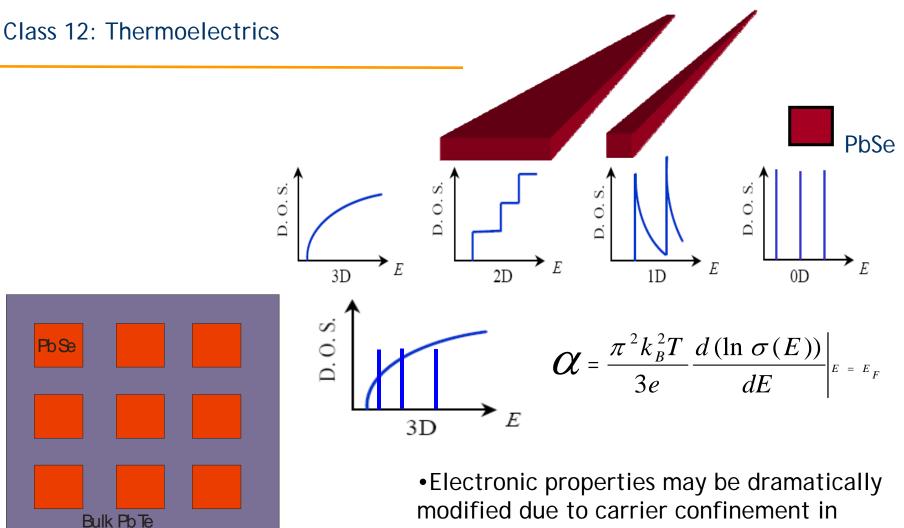
 $ZT = \frac{\sigma \alpha^2}{(\kappa_e + \kappa)}$

- ✤ Intermetallics with rare earths in intermediate valence states
 - ✤ Yb ^{2+,3+} (4f¹³-4f¹⁴); Ce ^{3+,4+} (4f¹-4f⁰)
 - Large Density of States at the Fermi Level
 - interaction between conduction electrons and partially localized 4f electrons leads to large α
 - very large numerator (power factor)
 - large denominator (thermal conductivity) low ZT



YbAI₃ and CePd₃

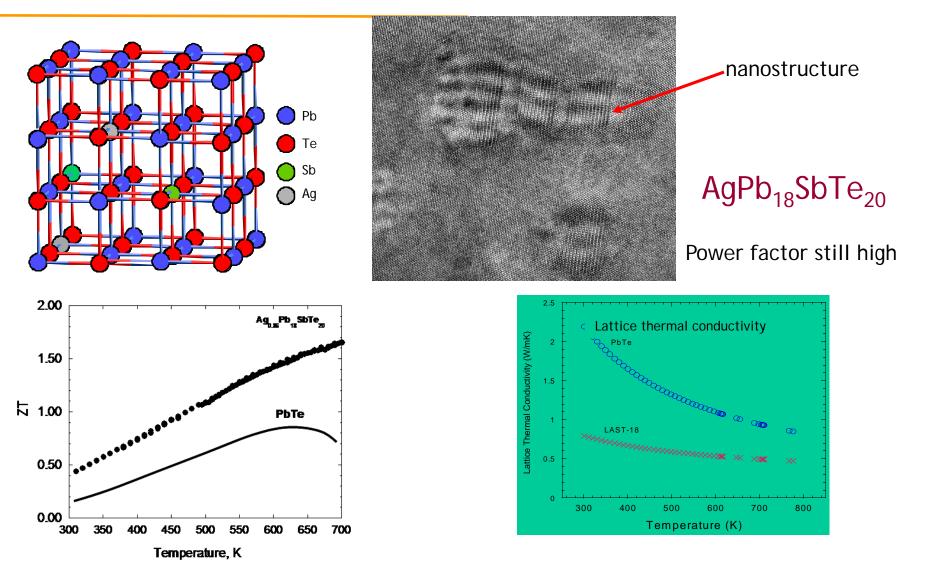




modified due to carrier confinement in nanostructures

 Thermoelectric power enhancement (rippling effect on DOS)

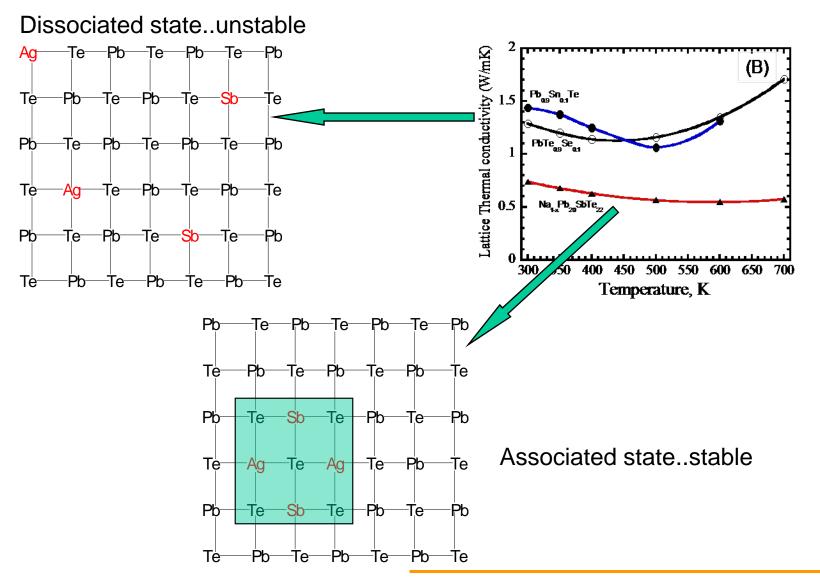
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Kanatzidis et al Science, 2004, 303, 818

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